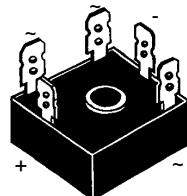
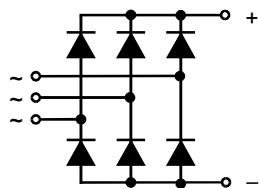


Three Phase Rectifier Bridge

$I_{dAVM} = 25 \text{ A}$
 $V_{RRM} = 1200-1800 \text{ V}$

V_{RSM} V	V_{RRM} V	Type
600	600	VUO 25-06N08
1200	1200	VUO 25-12N08
1400	1400	VUO 25-14N08
1600	1600	VUO 25-16N08
1800	1800	VUO 25-18N08



Symbol	Test Conditions	Maximum Ratings		
I_{dAV}	$T_c = 85^\circ\text{C}$, module	20	A	
I_{dAVM}	$T_c = 63^\circ\text{C}$, module	25	A	
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	380 400	A A
	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	360 400	A A
I^2t	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	725 750	A^2s A^2s
	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	650 650	A^2s A^2s
T_{VJ}			-40...+150	$^\circ\text{C}$
T_{VJM}			150	$^\circ\text{C}$
T_{stg}			-40...+150	$^\circ\text{C}$
V_{ISOL}	50/60 Hz, RMS $I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ min}$ $t = 1 \text{ s}$	2500 3000	V~ V~
M_d	Mounting torque	(M5) (10-32 UNF)	$2 \pm 10 \%$ $18 \pm 10 \%$	Nm lb.in.
Weight	typ.		22	g

Symbol	Test Conditions	Characteristic Values		
I_R	$T_{VJ} = 25^\circ\text{C}$; $T_{VJ} = T_{VJM}$	$V_R = V_{RRM}$ $V_R = V_{RRM}$	≤ 0.3 ≤ 5.0	mA mA
V_F	$I_F = 150 \text{ A}$;	$T_{VJ} = 25^\circ\text{C}$	≤ 2.2	V
V_{T0}	For power-loss calculations only		0.85	V
r_T			12	$\text{m}\Omega$
R_{thJC}	per diode; DC current		9.3	K/W
	per module		1.55	K/W
R_{thJH}	per diode; DC current		10.2	K/W
	per module		1.7	K/W
d_s	Creeping distance on surface		12.7	mm
d_A	Creepage distance in air		9.4	mm
a	Max. allowable acceleration		50	m/s^2

Data according to DIN IEC 60747 and refer to a single diode unless otherwise stated.
IXYS reserves the right to change limits, test conditions and dimensions.

Features

- Package with $1/4"$ fast-on terminals
- Isolation voltage 3000 V~
- Planar passivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- UL registered E 72873

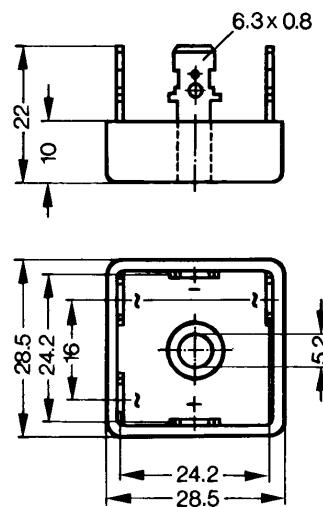
Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Advantages

- Easy to mount with one screw
- Space and weight savings
- Improved temperature and power cycling

Dimensions in mm (1 mm = 0.0394")



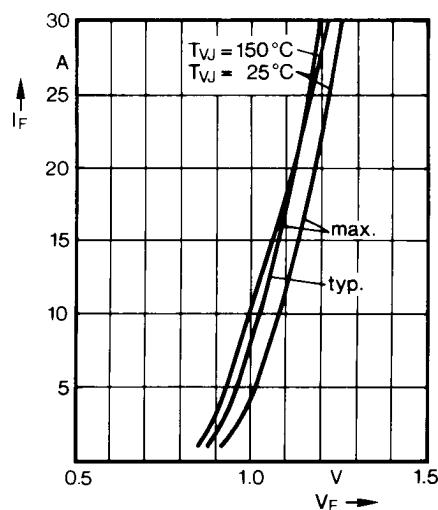


Fig. 1 Forward current versus voltage drop per diode

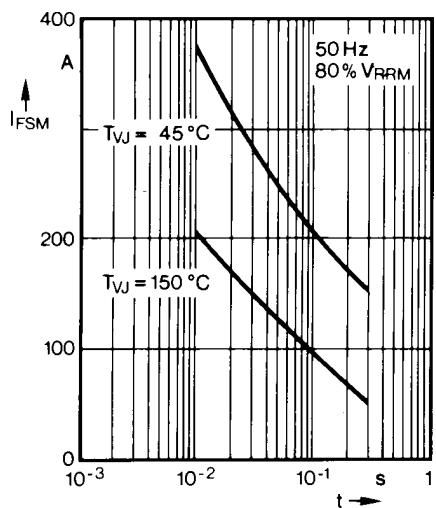


Fig. 2 Surge overload current per diode
 I_{FSM} : Crest value. t: duration

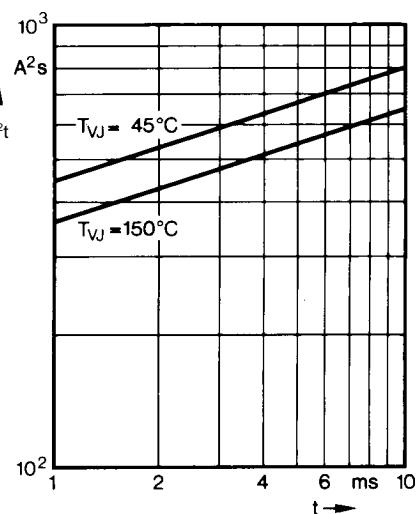


Fig. 3 I^2t versus time (1-10 ms)
per diode

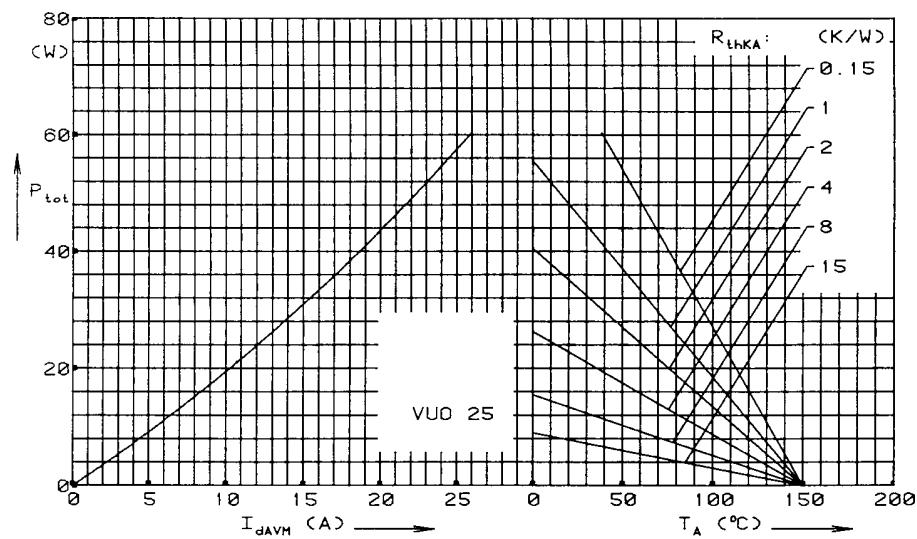


Fig. 4 Power dissipation versus direct output current and ambient temperature

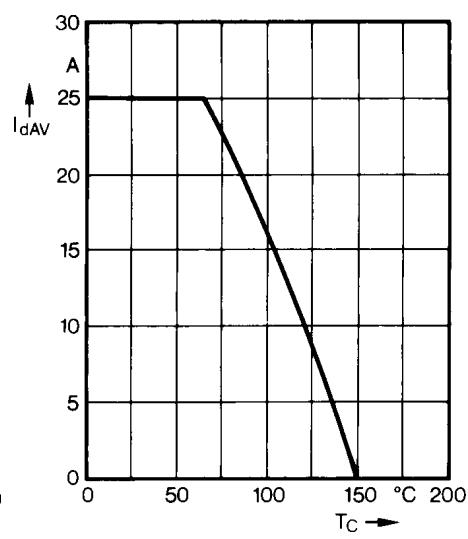


Fig. 5 Maximum forward current at case temperature

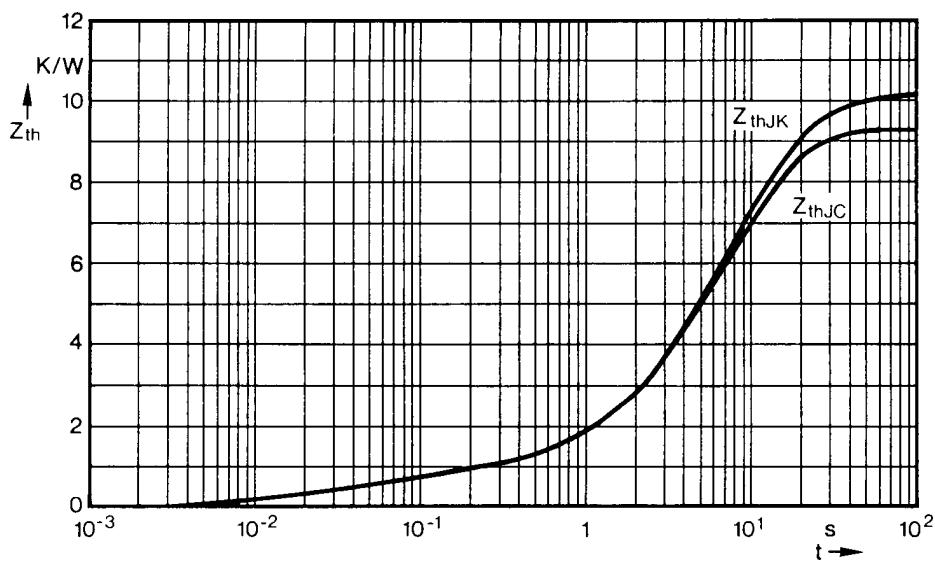


Fig. 6 Transient thermal impedance per diode

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.194	0.024
2	0.556	0.07
3	2.25	5.8
4	6.3	8.5
5	0.9	28.0

Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.194	0.024
2	0.556	0.07
3	2.25	5.8
4	6.3	8.5
5	0.9	28.0